# LDD-1137 / LASER-DIODE-DRIVER DATASHEET



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# Advanced OEM Laser Diode Driver with Laser Power Control [LPC optional]



#### **Description:**

The LDD-1137 is a specialized laser diode driver, able to precision-drive laser diodes in continuous and pulsed operation. New emerging technologies like eGaN FETs enable faster pulses, improved wave forms and better efficiency. A new processing core enables a faster processor connection to the powerful FPGA, more interfaces, more precise timing, additional functions and much more, while still maintaining a 1.5 mA resolution with much higher current and keeping a very low output ripple.

Equipped with optional light measurement circuitry, the LDD-1137-LPC can also be operated as a Laser Power Controller (LPC).

The LDD-1137 offers various safety features, including an input for laser diode temperature monitoring. They are fully digitally controlled; their firmware is upgradeable to offer various communication options and to meet specific customer requirements.

#### **Features**

#### **Input Characteristics:**

DC Input Voltage: 18 to 75 V

#### **Output Characteristics CW Operation:**

- Voltage: up to 70 V
- Current: up to 75 A (>60 A for a prolonged period may require additional cooling)

#### **Main Features:**

- Lookup Table with up to 64000 Samples for arbitrary current wave forms
- Error: Ultra-Fast Switch-off for optimal LD protection
- Configuration / Diagnosis: on PC (via USB / RS485 / Ethernet / CAN)
- Dimensions (L x W x H):
   118 mm x 171 mm x 48 mm
- Efficiency: >96 % (@ 50 % Duty cycle)
- Cooling: over Base Plate

#### Power Stage:

- Output Current: 0-75 A, ~0.2 % Ripple Parallel operation of multiple devices on request
- Temperature Coefficient, Typ: 20 ppm/K
- CW Current Resolution: 1.5 mA

#### **Pulse Version:**

- Pulse Generation: CW Chopping
- Pulse Rise Time: < 1 μs possible (Load dependant)</li>
- Pulse Frequency: TBD

#### Interfaces:

- USB 2.0, Ethernet
- RS485, CAN, SPI, I2C
- Pulse Input
- Interlock (Enable)
- Analog Input

#### Laser Power Control (LPC): [LPC option]:

- CW LPC: Configurable PID
- Start-up phase: Fully parameterizable

#### **Important Note:**

The following features will be added with a future firmware update, but are not yet useable:

- CAN, I2C, SPI
- LPC



Absolute Maximum Ratings		
Supply voltage (DC)	80 V	
Supply current (DC)	70 A	
Output current	80 A	

Operating Ratings		
Temperature	0 – 70 °C	
Humidity	5 – 95 %, non-condensing	



Warning

This is a high-power device.

Only operate this device in an enclosure.

Take necessary precautions to protect the operator.

#### **Electrical Characteristics**

Unless otherwise noted:  $T_A$  = 25 °C,  $U_{IN}$  = 24 V,  $R_{load}$  = 3.3  $\Omega$ 

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
DC Power S	supply Input:					
U <sub>IN</sub>	Supply voltage		18		75	V
U <sub>IN</sub> Ripple	Ripple tolerance	$U_{IN}$ never below $U_{IN}$ min or above			300	$mV_PP$
		U <sub>IN</sub> max				
Output						
Output:	1 0		04		7-	
I <sub>OUT</sub>	Current range		2*		75	Α
U <sub>OUT</sub>	Voltage range	$V_{IN} = 75 V$	0	70		V
I <sub>OUT_RIPPLE</sub>	Current ripple	lout > 2 A		TBD		mA
I <sub>OUT_RES</sub>	Current resolu-	Driver		1.5		mΑ
	tion					
V <sub>OUT_LIMIT</sub>	Output voltage			TBD		V
P <sub>OUT</sub>	Output power	$V_{LD}$ = 70 V, additional cooling			5000	W
$f_{CW}$	Current change	For $L_{Load}$ <100 nH, higher $f_{CW}$ are		TBD		kHz
		possible				
I <sub>OUT_SLOPE</sub>	Current slope	I <sub>out</sub> > 10 A		TBD		A/ns
_	limit					
System Cha	racteristics:					
η50%	Power efficiency	@ 50 % load		96		%
η100%	Power efficiency	@ 100 % load		98		%

<sup>\*</sup> Operation below this value is possible but the output current and measurement may show offsets outside of the specifications.

### Platform Bus Connector (PBC) X7

Unless otherwise noted:  $T_A = 25$  °C

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
<b>GPIO 1-8</b>	Characteristics:					
U <sub>IH</sub>	Logic high input threshold		2.35			V
U <sub>IL</sub>	Logic low input threshold				0.9	V
U <sub>IMAX</sub>	Absolute limit input voltage		-0.5		3.6	V
Output Cl	haracteristics:					
U <sub>OH</sub>	Logic high output voltage		2.9			V
U <sub>OL</sub>	Logic low output voltage				0.4	V
Rs	Series Resistor			100		Ω
Output Cl	haracteristics GND:					
I <sub>max</sub>	Absolute limit output current	Total GND Output (Fused)			±375	mA

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ESD Protection:					
$V_{PP}$	ESD	IEC61000-4-2 Level 4,	18		kV
		Contact Discharge			

# **Auxiliary Communication and GPIOs (AUX) X10**

Unless otherwise noted: T<sub>A</sub> = 25 °C

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
	aracteristics GPIO TT	L 1 and 2 (HW v1.20):	•			
U <sub>IH</sub>	Logic high input threshold		4.7			V
U <sub>IL</sub>	Logic low input threshold				1.8	V
U <sub>IMAX</sub>	Maximum input voltage		-0.5		7	V
Input Ch	aracteristics GPIO TT	L 1 and 2: (HW v1.30 and later):				
U <sub>IH</sub>	Logic high input threshold		3.9			V
U <sub>IL</sub>	Logic low input threshold				1.5	V
U <sub>IMAX</sub>	Maximum input voltage		-0.8		6	V
Input Ch	aracteristics Analog I	n 1V:				
V <sub>AN</sub>	Input voltage range	Analog input	0		1	V
BW	Bandwidth	Analog input		10	_	kHz
R <sub>IN</sub>	Input Resistance			10		kΩ
Input Ch	aracteristics Analog I	n 5V:				
V <sub>AN</sub>	Input voltage range	Analog input	0		5.3	V
BW	Bandwidth	Analog input		10		kHz
R <sub>IN</sub>	Input Resistance			23		kΩ
Input Ch	aracteristics Analog I	n 10V:				
V <sub>AN</sub>	Input voltage range	Analog input	0		10	V
BW	Bandwidth	Analog input		10		kHz
R <sub>IN</sub>	Input Resistance	ŭ i		37		kΩ
Output C	Characteristics GND:					
I <sub>max</sub>	Maximum output current	Total GND Output (Fused)	0		±375	mA
Output C	Characteristics 5V:					
I <sub>max</sub>	Maximum output current	5V Output (Fused)	0		±375	mA
ESD Pro	tection:					
V <sub>PP</sub>	ESD	IEC61000-4-2 Level 4, Contact Discharge		18		kV

# **High Performance Laser Diode Driver**Low-Ripple CW and Pulsed-Mode Operation up to 75 A / 70 V

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#### **Mini USB Connector X15**

Unless otherwise noted: T<sub>A</sub> = 25 °C

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Input Cha	racteristics:					
V <sub>IORM</sub>	Maximum Working				560	V
	Insulation Voltage					

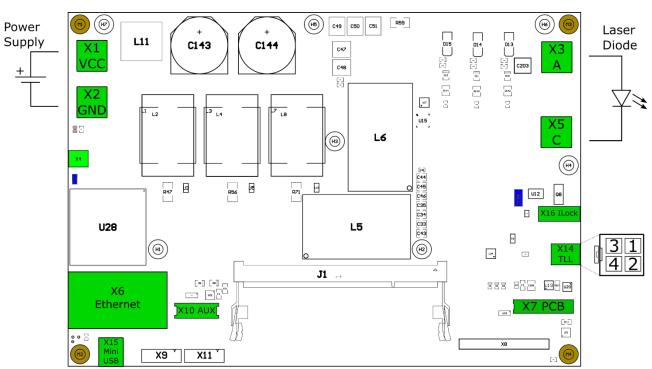
#### **Interlock Connector X16**

Unless otherwise noted:  $T_A$  = 25 °C

Symbol	Parameter	Test Conditions	Min	Тур	Max	Units
Input Characteristics Interlock:						
V <sub>IAct</sub>	Interlock active input voltage range	Voltage range which is detected as active input	3		30	V
V <sub>IORM</sub>	Maximum Working				630	V
	Insulation Voltage					

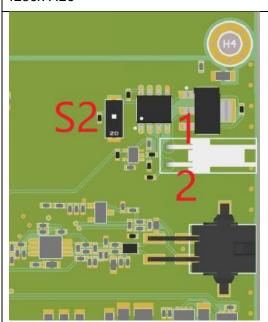
#### **Connectors**

#### Top view



#### **Interlock Connector X16**

#### ILock X16



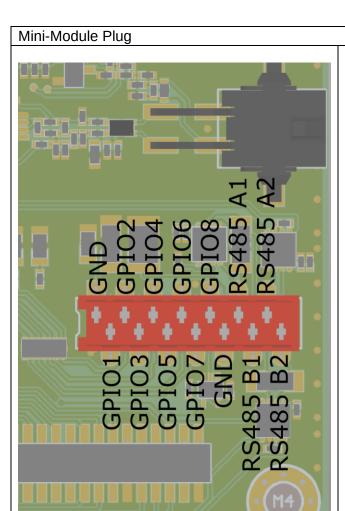
To enable the LDD apply a voltage between 3V and 30V between the Interlock + and Interlock – Pins. The Interlock Pins are galvanically isolated from the LDD.

The DIP-Switch S2 can be switched ON to override the Interlock functionality.

Connector: Molex 0022013027

Pin nr.	Name	Description
1	Interlock +	Interlock positive connection
2	Interlock -	Interlock negative connection

### Pin Configuration Platform Bus Connector (PBC) X7



Connector:

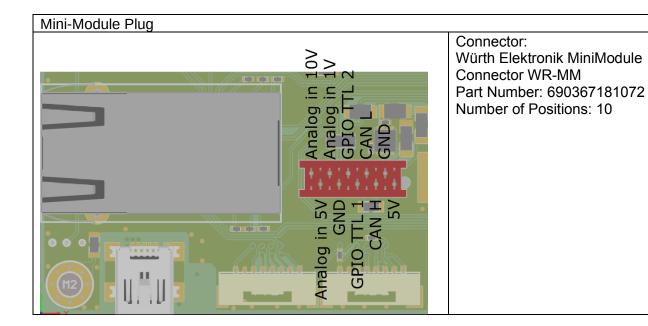
MICRO-MATCH SMD FTE Part Number: 8-188275-4 Number of Positions: 14

Centerline (Pitch): 1.27 mm [.05 in]

Pin nr.	Name	Description
1	GND EXT	Ground connection
2	GPIO 1	General-purpose input/output Pin 1
3	GPIO 2	General-purpose input/output Pin 2
4	GPIO 3	General-purpose input/output Pin 3
5	GPIO 4	General-purpose input/output Pin 4
6	GPIO 5	General-purpose input/output Pin 5
7	GPIO 6	General-purpose input/output Pin 6
8	GPIO 7	General-purpose input/output Pin 7
9	GPIO 8	General-purpose input/output Pin 8
10	GND EXT	Ground connection
11	RS485 A1	RS485 interface nr. 1A (TX+/RX+ or D+)
12	RS485 B1	RS485 interface nr. 1B (TX-/RX- or D-)
13	RS485 A2	RS485 interface nr. 2A (TX+/RX+ or D+)
14	RS485 B2	RS485 interface nr. 2B (TX-/RX- or D-)

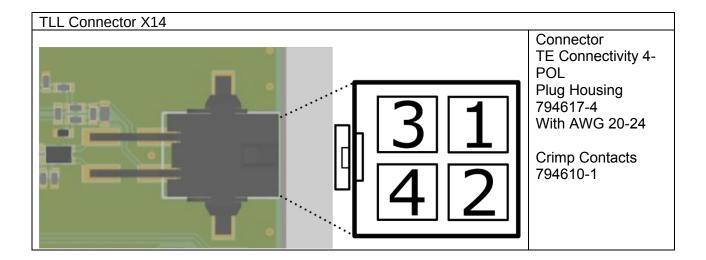
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## Pin Configuration Auxiliary Communication and GPIOs (AUX) X10



Pin nr.	Name	Description
1	5V	5V Output
2	GND	Ground connection
3	CANH	CAN High
4	CANL	CAN Low
5	GPIO TTL 1	General-purpose input with TTL Level
6	GPIO TTL 2	General-purpose input with TTL Level
7	GND	Ground connection
8	Analog In 1V	Analog Input 0-1V range
9	Analog In 5V	Analog Input 0-5V range
10	Analog In 10V	Analog Input 0-10V range

### Temperature and Laser Light (TLL) X14



Pin nr.	Name	Description
1	NTC A	NTC Connection
2	NTC B	NTC Connection
3	PD C	Photo Diode Cathode
4	PD A	Photo Diode Anode

Matching Cable: CAB-6156

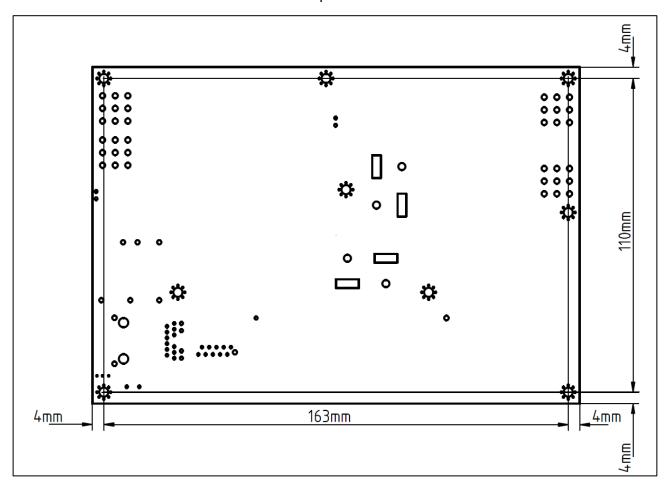
#### Mini USB Connector X15

The Mini USB Connector X15 can be used to communicate with the LDD using the meCom communications protocol or the Configuration Software. It is electrically isolated.



#### **Dimensions**

Top View



Mounting holes in the corner are 3.2 mm holes for M3 screws.

# **High Performance Laser Diode Driver**Low-Ripple CW and Pulsed-Mode Operation up to 75 A / 70 V

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#### **Pulse and CW comparison**

	CW	Pulse
CW operation	Yes	Yes
Signal generator Pulses	Yes	Yes
CW chopping	No	Yes
Ripple	Less	Normal

The Pulse version is recommended if risetimes below 100 us are desired.

The Pulse version can be operated exactly like the CW version, or by using the dedicated Pulse functions. The dedicated pulse functions utilize CW-chopping to achieve faster pulses. The Pulse version also contains less output filters, which enables faster risetimes while slightly increasing the ripple.

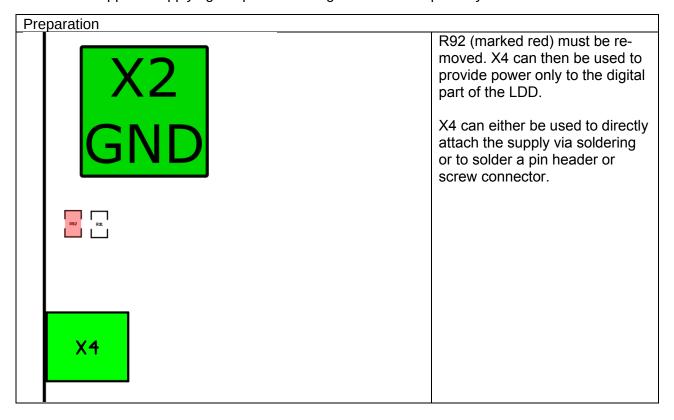
Note: the graph in the Configuration Software displays the high-side current measurement, therefore chopped pulses cannot be observed properly in the graph as the current keeps flowing internally during chopping.

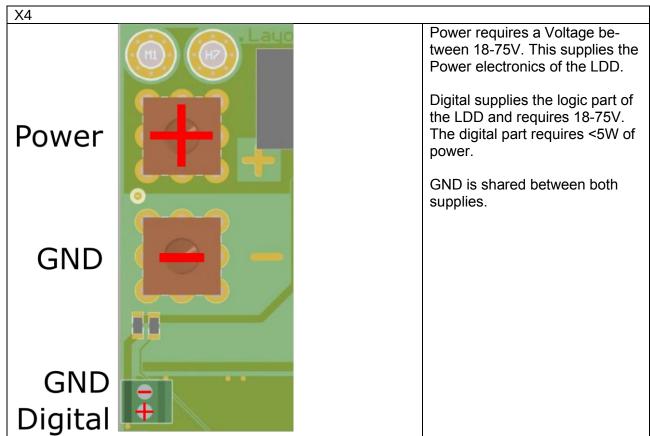
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### **Separate supply for Power and Digital parts**

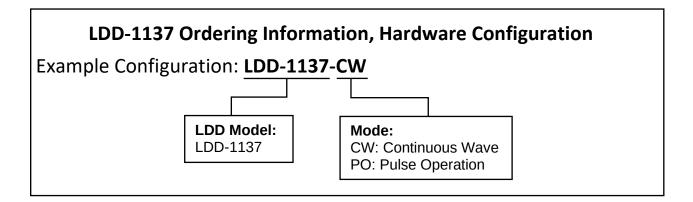
The device supports supplying the power and digital sections separately.





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## **Ordering Information**



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# High Performance Laser Diode Driver Low-Ripple CW and Pulsed-Mode Operation up to 75 A / 70 V $\,$

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# **Change History**

Date of change	Doc/Ver- sion	Changed / Approved	Change / Reason
4 March 2021	В	PV / MR	<ul> <li>Add Change History</li> <li>First prototype measurement data inserted</li> <li>New layout template used</li> </ul>
2 December 2021	С	PV/RS	<ul><li>New HW v1.20 changes</li><li>High power warning</li><li>Measurement plots</li></ul>
7 September 2022	D	PV / RS	<ul> <li>Fixed RS485 polarity</li> <li>Added X14 pinout</li> <li>Adjusted TTL levels for HW v1.30</li> </ul>